Chip Silicon Rectifier

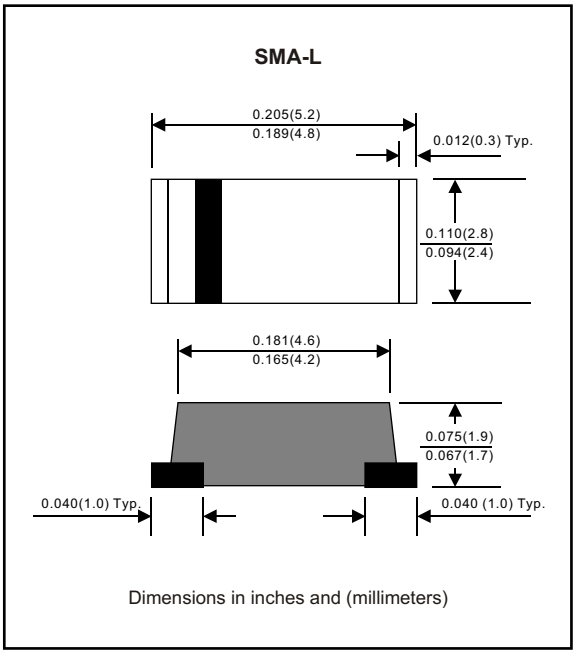
Formosa MS

HFM201-L THRU HFM207-L

Ultra fast recovery type

Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-O Utilizing Flame Retardant Epoxy Molding Compound.
- For surface mounted applications.
- Exceeds environmental standards of MIL-S-19500 / 228
- Low leakage current.



Dimensions in inches and (millimeters)

Mechanical data

Case : Molded plastic, JEDEC DO-214AC
Terminals : Solder plated, solderable per MIL-STD-750, Method 2026
Polarity : Indicated by cathode band
Mounting Position : Any
Weight : 0.0015 ounce, 0.05 gram

MAXIMUM RATINGS *(AT T_A=25°C unless otherwise noted)*

PARAMETER	CONDITIONS	Symbol	MIN.	TYP.	MAX.	UNIT
Forward rectified current	Ambient temperature = 50°C	I_O			1.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC methode)	I_{FSM}			50	A
Reverse current	V_R = V_{RRM} T_A = 25°C	I_R			5.0	uA
	V_R = V_{RRM} T_A = 100°C				150	uA
Thermal resistance	Junction to ambient	R_{JA}		20		°C / W
Diode junction capacitance	f=1MHz and applied 4vDC reverse voltage	C_J		25		pF
Storage temperature		T_{STG}	-55		+150	°C

SYMBOLS	MARKING CODE	V_{RRM} *1 (V)	V_{RMS} *2 (V)	V_R *3 (V)	V_F *4 (V)	T_{RR} *5 (nS)	Operating temperature (°C)
HFM201-L	H21	50	35	50	1.0	50	-55 to +150
HFM202-L	H22	100	70	100			
HFM203-L	H23	200	140	200			
HFM204-L	H24	400	280	400	1.3		
HFM205-L	H25	600	420	600	1.7	75	
HFM206-L	H26	800	560	800			
HFM207-L	H27	1000	700	1000			

*1 Repetitive peak reverse voltage
*2 RMS voltage
*3 Continuous reverse voltage
*4 Maximum forward voltage
*5 Reverse recovery time

RATING AND CHARACTERISTIC CURVES (HFM201-L THRU HFM207-L)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

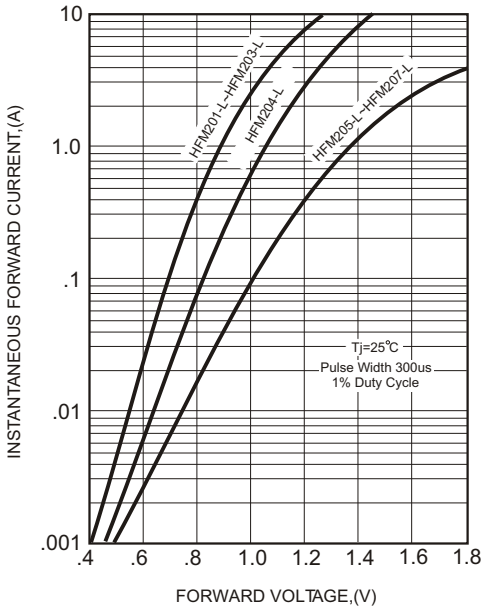


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

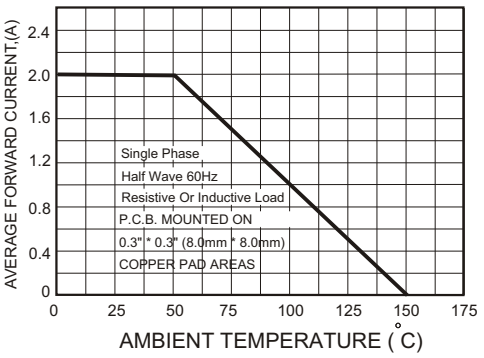
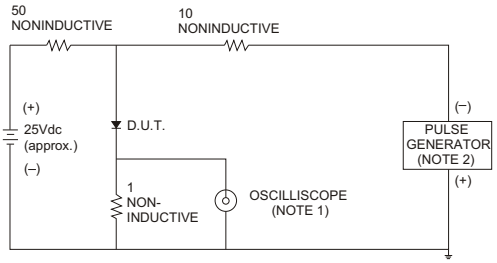


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

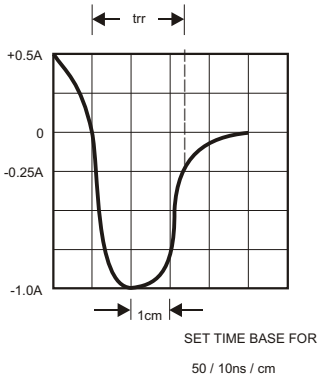


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

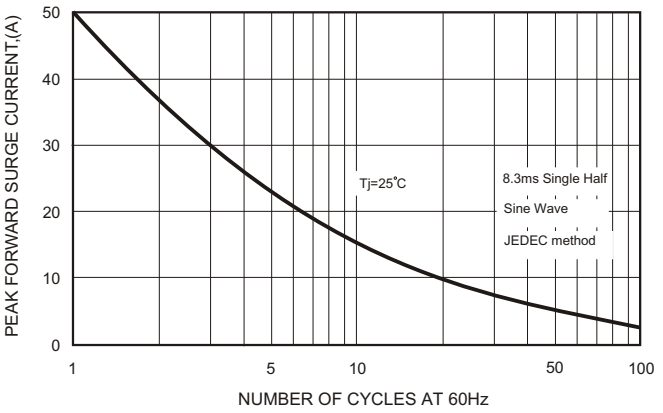
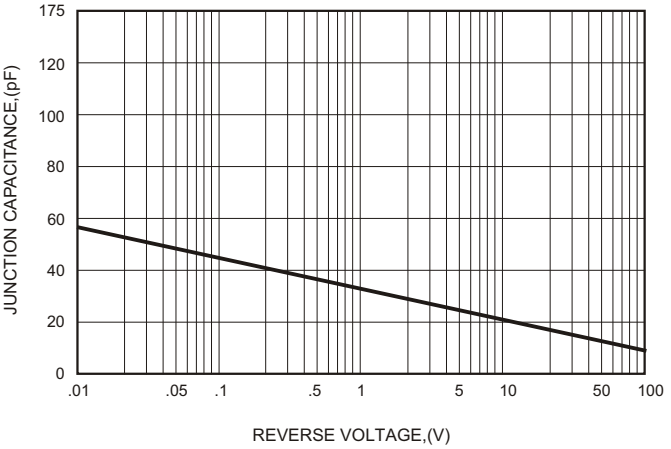



FIG.5-TYPICAL JUNCTION CAPACITANCE